

#### **5 A Schottky Barrier Rectifier**

package.

#### **DESCRIPTION**

#### **KEY FEATURES**

Guard Ring die construction for

Internal heat sink locking tabs

In Microsemi's new Powermite® SMT package, these high efficiency Schottky rectifiers offer the power handing capabilities previously found only in much larger packages. They are ideal for SMD applications that operate at high frequencies.

In addition to its size advantages, Powermite<sup>®</sup> package features include a full metallic bottom that eliminates the possibility of solder flux entrapment during assembly, and a unique locking tab acts as an integral heat sink. Its innovative design makes this device ideal for use with automatic insertion equipment.

IMPORTANT: For the most current data, consult MICROSEMI's website: http://www.microsemi.com

|   | at   | high   |  |
|---|------|--------|--|
| d | ، ما | a full |  |

- Low forward voltage.
   Full metallic bottom eliminates flux entrapment
- Compatible with automatic insertion equipment

High power surface mount

transient protection.

 Low profile-maximum height of 1.1 mm supplied in 16 mm tape reel- 5000 units/ 13" reel.

| ABSOLUTE MAXIMUN | I RATINGS | S AT 25° C |
|------------------|-----------|------------|
| (UNLESS OTHERW   | ISE SPEC  | IFIED)     |
|                  |           |            |

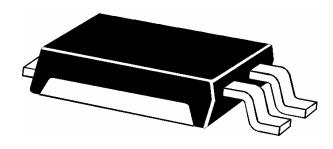
| (GNEE33 GTTERWISE SPECIFIED)  |  |             |      |  |  |
|---|--|-------------|------|--|--|
| Rating  | Symbol   | Value       | Unit |  |  |
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage  | V <sub>RRM</sub><br>V <sub>RWM</sub><br>V <sub>R</sub> | 40          | V    |  |  |
| RMS Reverse Voltage   | V <sub>R (RMS)</sub>                                   | 28          | V    |  |  |
| Average Rectified Output Current  | Io   | 5           | Α    |  |  |
| Non-Repetitive Peak Forward Surge Current<br>8.3ms Single half sine wave Superimposed<br>on Rated Load@ T <sub>c</sub> =90 °C | I <sub>FSM</sub>                                       | 100         | А    |  |  |
| Storage Temperature   | T <sub>STG</sub>                                       | -55 to +150 | °C   |  |  |
| Junction Temperature  | Τ <sub>J</sub>   | -55 to +125 | °C   |  |  |

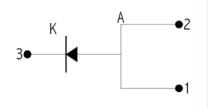
# THERMAL CHARACTERISTICS (UNLESS OTHERWISE SPECIFIED)

| (ONLESS OTHERWISE SPECIFIED) |                |     |         |  |
|------------------------------|----------------|-----|---------|--|
| Thermal Resistance           |                |     |         |  |
| Junction-to Case (Bottom)    | $R_{	heta JC}$ | 3.2 | °C/Watt |  |
|                              |                |     |         |  |

#### APPLICATIONS/BENEFITS

- Switching and Regulating Power Supplies
- Silicon Schottky (hot carrier) rectifier for minimal reverse voltage recovery
- Elimination of reverse-recovery oscillations to reduce need for EMI filtering
- Charge Pump Circuits.
- Reduces reverse recovery loss due to low I<sub>RM</sub>.
- Small foot print
   190 X 270 mils (1:1 Actual size)
   See mounting pad details on pg 3



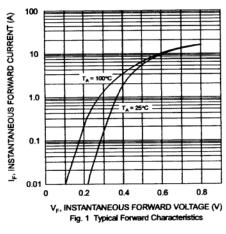


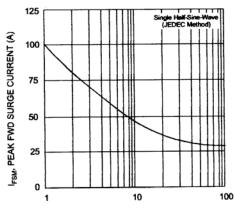


## **5 A Schottky Barrier Rectifier**

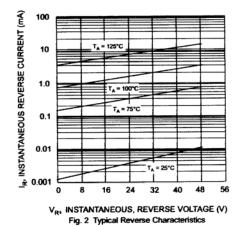
| ELECTRICAL PARAMETERS @ 25°C (unless otherwise specified) |                 |   |     |                      |           |       |
|---|-----------------|---|-----|----------------------|-----------|-------|
| Parameter   | Symbol          | Conditions  | Min | Тур.                 | Max       | Units |
| Forward Voltage (Note 1)                                  | V <sub>F</sub>  | $I_F = 5 \text{ A}$ , $T_j = 25 ^{\circ}\text{C}$<br>$I_F = 5 \text{ A}$ , $T_j = 125 ^{\circ}\text{C}$<br>$I_F = 10 \text{ A}$ , $T_j = 25 ^{\circ}\text{C}$ |     | 0.47<br>0.45<br>0.62 | 0.54      | V     |
| Reverse Break Down Voltage<br>(Note 1)                    | V <sub>BR</sub> | $I_F = 10 \text{ A}$ , $T_j = 125 ^{\circ}\text{C}$<br>$I_R = 0.5 \text{ mA}$   | 40  | 0.59                 |           | V     |
| Reverse Current (Note1)                                   | I <sub>F</sub>  | $V_R = 40 \text{ V}, T_j = 25^{\circ}\text{C}$<br>$V_R = 40 \text{ V}, T_j = 125 ^{\circ}\text{C}$  |     | 0.030<br>2.5         | 0.5<br>20 | mA    |
| Capacitance   | Ст              | $V_R = 4 \text{ V}; F = 1 \text{ MH}_Z$   |     | 250                  |           | pF    |

Note: 1 Short duration test pulse used to minimize self – heating effect





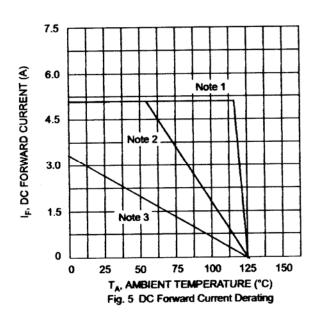
NUMBER OF CYCLES AT 60 Hz Fig. 3 Max Non-Repetitive Peak Fwd Surge Current

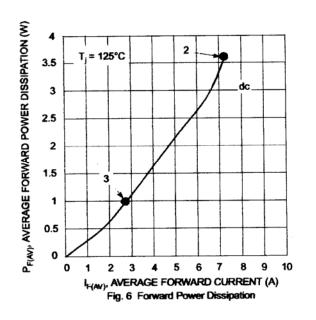


V<sub>R</sub>, REVERSE VOLTAGE (V) Fig. 4 Typical Junction Capacitance

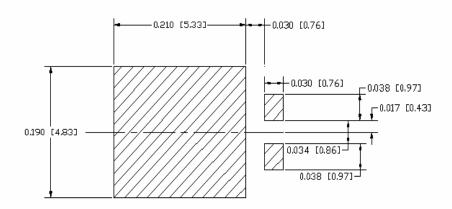


#### **5 A Schottky Barrier Rectifier**





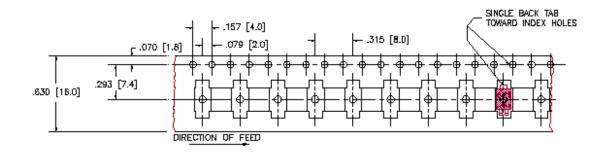
- Notes: 1.  $T_A = T_{SOLDERING\ POINT}$ ,  $R_{\Theta JS} = 3.2$ °C/W,  $R_{\Theta sa} = 0$ °C/W.
  - 2. Device mounted on GETEK substrate, 2" x 2", 2 oz. copper , double-sided , cathode pad dimensions 0.75" x 1.0", anode pad dimensions 0.25" x 1.0".  $R_{\Theta JA}$  in range of 15-30° C/W.
  - 3. Device mounted on FRA-4 substrate, 2" x 2", 2 oz. copper, single-sided, pad layout  $R_{\Theta IA}$  in range of 65° C/W. See mounting pad below.



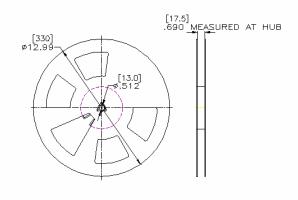


## **5 A Schottky Barrier Rectifier**

16 mm TAPE

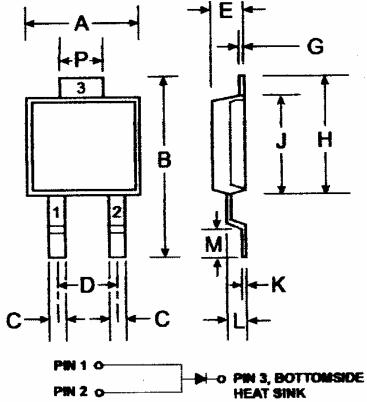


#### 13 INCH REEL





## **5 A Schottky Barrier Rectifier**



| POWERMITE®3          |          |      |  |
|----------------------|----------|------|--|
| Dim                  | Min      | Max  |  |
| A                    | 4.03     | 4.09 |  |
| В                    | 6.40     | 6.61 |  |
| С                    | .889 NOM |      |  |
| D                    | 1.83 NOM |      |  |
| E                    | 1.10     | 1.14 |  |
| G                    | .178 NOM |      |  |
| н                    | 5.01     | 5.17 |  |
| J                    | 4.37     | 4.43 |  |
| K                    | .178 NOM |      |  |
| L                    | .71      | .77  |  |
| M                    | .36      | .46  |  |
| P                    | 1.73     | 1.83 |  |
| All Dimensions in mm |          |      |  |

Note:

Pins 1 & 2 must be electrically connected at the printed circuit board.



## **5 A Schottky Barrier Rectifier**

| • | NOTES: |
|---|--------|
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|   |        |
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|   |        |
|   |        |
|   |        |
|   |        |
|   |        |
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